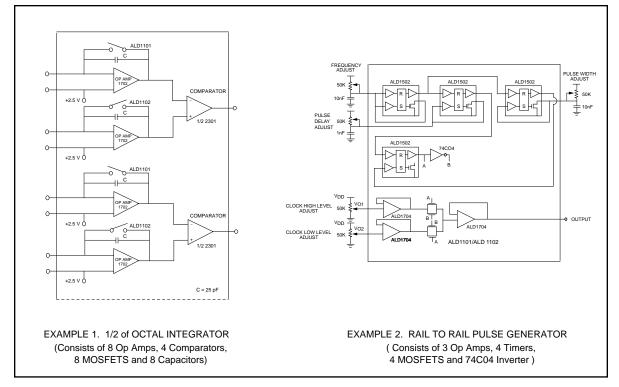
A PRACTICAL SOLUTION to CUSTOM LINEAR I.C.'s — ALD's "FUNCTION-SPECIFIC" ASIC PROGRAM

"FUNCTION-SPECIFIC" is ALD's standard cell approach to custom linear circuits with the standard cells being ALD standard products. It allows you to design with completely specified standard linear I.C.'s and implement your custom I.C. - or - go into production with standard I.C.'s and transition into your custom I.C. - with no redesigns - as your production volume increases.

Standard Part = Standard Cell = Kit Part Easy to implement.

- Step I. Order your "Function-Specific" Design Kit.
- Step II. Design your circuit with ALD standard products.
- Step III. Breadboard and prove your design.
- Step IV. Decide on the package and pin-out.
- Step V. Send your circuit to ALD for a quotation.
- Step VI. Place order, wait 12 -16 weeks, and receive your "Function-Specific" Circuit.

No I.C. design techniques or software to learn. A full custom, high performance ASIC Program. There is a nonrecurring engineering charge. All standard packages, including SOIC's and dice, are available. Hi Rel processing available.



Examples of "FUNCTION-SPECIFIC" Linear I.C.'s

415 Tasman Drive Sunnyvale, California 94089-1706 Telephone: 408/747-1155 Fax: 408/747-1286 http:\www.aldinc.com

What is ALD's "FUNCTION-SPECIFIC" Approach?

- No I.C. design techniques or software to learn. Optional simulation models, macromodels and subcircuits are available.
- Design and breadboard with completely specified, off the shelf, standard I.C.'s as you normally do.
- Minimizes risk proves your design works before committing to a custom chip.
- If you're not sure your volume justifies a custom chip just yet, go into production with standard ALD linear I.C.'s and transition to a custom I.C. when it suits you -AND- without a major redesign.
- Optimizes your surface mount program use an SOIC package and combine your linear I.C.'s onto one chip.
- FAST: 12-16 weeks is the normal lead time once your "Function-Specific" order is placed -AND- you don't have to spend weeks or months becoming an I.C. designer in order to develop your circuit.
- Low power, low voltage, precision Silicon Gate CMOS using ALD's precision ACMOS process provides 5V linear I.C.'s that match-up with the 5V digital circuits you're using in today's low voltage, low power systems.

How Does ALD's "Function-Specific" Design Approach Compare?

COMPARISON OF VARIOUS DESIGN APPROACHES

Relative Comparison Scale of 0 to 10

	Full Customl	"Function- Specific" ASIC	Cell Library ASIC	Linear Array ASIC	Standard Product
Circuit Performance	10	10	7	5	10
I.C. Design Cost	10	2	2	2	0
Design & Prototype Ease	1	10	3	3	10
Prototype Development Time	10	5	5	3	0
Die Size Optimization	10	7	7	5	NA
Project Cost	10	2	3	2	0
First Time Prototype Success Rate	4	10	7	5	NA
Redesign Flexibility	4	10	7	5	10
Test Engineering Cost	10	2	5	8	0
Production Unit Cost	3	3	7	10	2
Per Function Reliability	10	10	5	5	2
P C Board Cost	1	1	2	2	5
Production Cost	1	2	2	2	5
Design Security	10	8	8	8	1
Ease of Field Testing	1	10	2	2	10
Production Quantity Time	10	4	4	4	2

Packaging, Hi Rel, and Non-Standard Cells

- Your packaging requirements are met with industry standard PDIP, CDIP, SOIC, PLCC, and DICE. Standard pin counts are 8, 14, 16, 18, 20, 22, 24, 28, 40, 48, 54, 68 and 84. Special packages are available.
- High reliability military processing is available, as is ALD's industrial enhanced reliability "A+" program.
- New products (=standard cells) are continually being announced by ALD. Should your design require cells not currently announced, check with us to see if what we have coming fits in with your plans. In the event ALD's "Function-Specific" approach doesn't meet your needs, ALD will work with you on your "full-custom I.C."

Products

The heart of a standard cell program is having high performance, completely specified, leading edge, useful linear cells designed with integration in mind. ALD's product line provides this:

Op amps with:

- · Rail to Rail inputs and outputs
- $10^{12} \Omega$ input impedance
- Dual or single supply
- · Low power, low voltage

Timers/Oscillators with:

- 99% accuracy
- Up to 1.4 to 2.5 MHz frequency
- 1V to 12V supply voltage
- · Low power

Comparators with:

- Response times of 120ns to 650ns
- Output current of 24mA to 60mA
- Low power: 55µA to 250µA
- $10^{12} \Omega$ input impedance
- Low voltage, dual or single supply

MOSFET Pairs with:

- N channel and P channel
- Low voltage, low power

Next page shows a summary. See individual data sheets for complete specifications.

Frequently Asked Questions Regarding "Function-Specific" Circuits

- Q: Is this like a linear array?
- A: No. An array is a chip filled with fixed transistors, diodes and passives which you must design with and interconnect - following I.C. design rules and sometimes using specialized software and hardware. "Function-Specific" is a standard cell approach with defined I.C.'s (standard parts) you configure using your standard design practices, resulting in a completely custom chip. In "Function-Specific" you have completely characterized higher level building blocks (such as various operational amplifiers) that were carefully developed to be integrated.
- Q: What about critical nodes? Will my circuit work in chip form?
- A: ALD has already solved this problem. The critical nodes are within the devices themselves inside the op amps, timers, comparators, etc. All the normal input, output, and power supply nodes are noncritical and designed to withstand parasitic stray capacitances. As a result, integrating a variety of devices on a single chip presents no particular problem as long as the breadboard works.
- Q: Is "SPICE" available for simulation?
- A: ALD supports simulation models, subcircuits and macromodels. PSPICE with this simulation can be conducted by either a customer or by ALD personnel, as a supplement to the breadboard.
- Q: Why does it take 12-16 weeks?
- A: Because each I.C. is different and must have a unique, complete custom mask set generated, wafers fabricated and tested, units packaged, final tested, and shipped.
- Q: Can resistors and capacitors be integrated in a "Function-Specific" I.C.?
- A: Yes, resistors and capacitors can be integrated on your custom linear I.C.
- Q: Can I put in 1% precision resistors and different types of capacitors?
- A: No, but you can bring out the leads where you want them and place your precision passives off the chip.
- Q: Can digital circuits be put on a "Function-Specific" chip?
- A: Yes, contact ALD for a list of digital SSI and MSI level gates that are currently available in the ALD "Function Specific" digital library.
- Q: Are diodes available on chip?
- A: You can use the MOSFETS in a diode-connected configuration.
- Q: Can I have isolated circuits on one chip?
- A: There are typically 120dB isolation between circuits.
- Q: How much does it cost?
- A: Since it is a full custom program, it depends on the complexity of the circuitry involved. There are two cost components. The first is a one time, nonrecurring engineering cost for setting up and implementing the project. The second component is a unit cost, which depends on the complexity, packaging, testing, and volume of the ASIC chip. An I.C. chip usually costs much less than buying the individual parts and assembling them onto a circuit board.

FSK11 DESIGN KIT

Part No.	Description	Maximum Vos	Quantity	Part No.	Description	Quantity
ALD2701	Op Amp, dual micropower	10.0	4	ALD2301	Dual comparator, 60mA	2
ALD2701A	Op Amp, dual micropower	2.0	4	ALD4302	Quad comparator, fast	2
ALD1701	Op Amp, micropower	4.5	8			
ALD1701G	Op Amp, micropower	10.0	4	ALD555	Precision timer	4
ALD1701A	Op Amp, micropower	0.9	2	ALD1502	High frequency timer	4
ALD1702	Op Amp, oscillation resistant	4.5	8	ALD2502	Dual, high frequency timer	4
ALD1702A	Op Amp, oscillation resistant	0.9	2			
ALD1703	Op Amp, general purpose	10.0	10	ALD1101	N-channel dual MOSFET	4
ALD1704	Op Amp, JFET replacement	4.5	8	ALD1102	P-channel dual MOSFET	4
ALD1704A	Op Amp, JFET replacement	0.9	2			
ALD1706	Op Amp, ultra micropower	4.5	8		"Function-Specific" Design Manual	1
ALD1706A	Op Amp, ultramicropower	0.9	2		Data Sheets	All

"FUNCTION-SPECIFIC" PARTS LIST

OPERATIONAL AMPLIFIERS Maximum Input Bias Input Voltage Supply Voltage Maximum Input Offset Maximum Input Offset Part No. Description Bandwidth Slew Rate Maximum Packages Power . Current Range Range . Voltage . Current 8L SOIC, PDIP, CDIP, DICE ±1V to ±6V 2V to 12V ALD1701 CMOS, Rail to Rail, 0.7MHz 0.7V/µsec 30pA Vss to Vdd 1.25mW 0.9mV, 2mV 25pA Micropower 4.5mV, 10mV ±2V to ±6V 8L SOIC, PDIP, CDIP, DICE ALD1702 CMOS. Rail to Rail. 1.5MHz 2.1V/usec 30pA Vss to Vdd 10mW 0.9mV. 2mV 25pA Oscillation resistant 4V to 12V 4.5mV within 150mV of ±2V to ±6V 4V to 12V 8L SOIC, PDIP, CDIP, DICE ALD1703 CMOS, Low Cost 1.5MHz 2.1V/µsec 50pA 12.5mW 10mW 30pA Vss or Vdd ALD1704 CMOS, Low cost, 8L SOIC, PDIP, CDIP, DICE ±3.25V to ±6V 0.9mV, 2mV 4.5mV, 10mV JFET replacement 2.1MHz 5V/µsec 20pA Vss to Vdd 45mW 15pA 6.5V to 12V CMOS, Rail to Rail, ALD1706 Very low power 0.3MHz 0.17V/µsec 30pA Vss to Vdd 0.2mW ±1V to ±6V 0.9mV, 2mV 4.5mV, 10mV 25pA 8L SOIC, PDIP, 2V to 12V CDIP, DICE ALD2701 Dual CMOS, 14 L SOIC, 8L PDIP, CDIP, DICE Rail to Rail, micropower ±1V to ±6V 2mV, 5mV, 0.7MHz 0.7V/µsec 30pA Vss to Vdd 2.5mW 25pA 2V to 12V 10mV

VOLTAGE COMPARATORS

Part No.	Description	LS TTL Fanout	Minimum Output Current	5mV Overdrive Response Time	Supply Voltage	Maximum Supply Current	Maximum Input Bias Current	Maximum Input Offset Current	Maximum Input Offset Voltage	Packages	
ALD2301	Dual CMOS Open 30 Collector Outputs		24mA	650 ns	+3V to +12V ±1.5V to ±6V	90µA	200 pA	200 pA	2- 20 mV	8L SOIC, PDIP, CDIP, DICE	
ALD4302	Quad CMOS Push-Pull Outputs	30	24mA	400 ns	+3V to +12V ±1.5V to ±6V	250μΑ	200 pA	200 pA	5-15mV	14L SOIC, PDIP, CDIP, DICE	

TIMERS/OSCILLATORS

Part No.	Configuration	Supply Voltage	Power Dissipation µW/Timer		Accu %	iracy %		Operating acy, MHz	Trigger/T Currer		Packages
			Тур	Max	Тур	Min	Тур	Guaranteed	Тур	Max	
ALD555	Single	2-12V	500 @ 5V	900	99	98	2.0	1.4	0.001	0.2	8L SOIC, PDIP,
ALD1502	Single	2-12V	250 @ 5V	450	99	97	2.5	1.5	0.01	0.4	CDIP, DICE
ALD2502	Dual	2-12V	250 @ 5V	450	99	97	2.5	1.5	0.01	0.4	14L SOIC, PDIP, CDIP, DICE

	МО	TRAM	ISIST	ORS				ON-CHIP PASSIVE COMPONENTS								
Part No.	Channel	V	Т	IDS (on)		Gm	Packages	Passive	Туре	Value	Range	Tolerance	Matc	hing	Temperature	
		V	/	m	mA umho		umho		Component		Min	Max		Min	Max	Coefficient
		Тур	Max	Min	Тур			[Resistor	lon	1kΩ	25kΩ	±10%	±0.2%	±1%	
ALD 1101	Dual N	0.70	1.00	30	40	10,000	8L PDIP, CDIP,			Implanted	1kΩ	10MΩ	±25%	-	±2%	2000ppm/°C
							T0-99, DICE	[Polysilicon	10Ω	1kΩ	±20%	±0.5%	±2%	1200ppm/°C
ALD 1102	Dual P	-0.70	-1.00	-11	-16	4,000	-		Capacitor	MOS	0.25pF	1000pF	±10%	±0.1%	±1%	30ppm/°C